

μ PD5753T7G

SiGe/CMOS Integrated Circuit 4 × 2 IF Switch Matrix with Tone/Voltage Controller

R09DS0014EJ0100 Rev.1.00 Feb 22, 2011

FEATURES

4 independent IF channels, integral switching to channel input to either channel output

• 4 × 2 switch matrix with integrated switch control - Tone/Voltage

- Switch's Enable/Disable function is linked with POLA input voltage level

• Switch's Enable condition : $V_{POLA} > 9.5 \text{ V}$

• Frequency range : f = 250 MHz to 2150 MHz

• High isolation : $ISL_{D/U} = 33$ dB TYP. @Worst mode • Insertion loss : $L_{INS} = 7$ dB TYP. @ $Z_S = Z_L = 50$ Ω

• Insertion loss flatness : $\Delta L_{INS} = 1.0 \text{ dB TYP}.$

20-pin 4 × 4 mm square micro lead package (20-pin plastic QFN (0.5 mm pitch))

APPLICATIONS

- DBS IF switching
- Multiswitch, Switch box
- 4×2 switching application for microwave signal

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μPD5753T7G-E1	μPD5753T7G-E1-A	20-pin plastic QFN	D5753	Embossed tape 12 mm wide
		(0.5 mm pitch)		Pin 6 to 10 face the perforation side of the tape
		(Pb-Free)		Qty 5 kpcs/reel
				 Dry packing specification (MSL 3 Equivalent)

Remark To order evaluation samples, please contact your nearby sales office.

Part number for sample order: μPD5753T7G



Observe precautions when handling because these devices are sensitive to electrostatic discharge.

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Supply Voltage	V_{DD}	+4.0	V
Logic mode Control Voltage	V_{MO}, V_{M1}	+4.0	V
(MO and M1)			
Power Dissipation Note	P _D	325	mW
Storage Temperature	T _{stg}	-55 to +125	°C
Operating Ambient Temperature	T _A	-40 to +85	°C
Input Power	Pin	+15	dBm
POLA Control Input Voltage	V_{POLA}	+25	V
(POLA1 and POLA2)			
TONE Signal Input Voltage	V_{TONE}	1	V_{p-p}

Note: Mounted on double-sided copper-clad $50 \times 50 \times 0.51$ mm laminates PWB, T_A = +85°C

RECOMMENDED OPERATING RANGE (TA = +25°C, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V_{DD}	+3.0	+3.3	+3.6	V
Operating Ambient Temperature	T_A	-40	+25	+85	°C
POLA Control Input Voltage	V_{POLA}	0	-	21	V
TONE Signal Frequency	f _{TONE}	18	22	26	kHz
TONE Signal Input Voltage	V_{TONE}	0.4	0.6	0.8	V_{p-p}

ELECTRICAL CHARACTERISTICS (T_A = +25°C, V_{DD} = +3.3 V, Z_S = Z_L = 50 Ω for each port, Worst mode, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Supply Current	I _{DD}	Non-RF,	_	1.9	3.0	mA
		Non control Signal/Voltage				
Insertion Loss 1	L _{INS} 1	$P_{in} = 0 \text{ dBm}, f = 0.95 \text{ GHz}$	_	6.5	8.5	dB
Insertion Loss 2	L _{INS} 2	P _{in} = 0 dBm, f = 2.15 GHz	_	7.5	9.5	dB
Isolation D/U Ratio 2 Note	ISL _{D/U} 2	P _{in} = 0 dBm, f = 2.15 GHz	28	33	_	dB
Output Return Loss 1	RL _{out} 1	$P_{in} = 0$ dBm, f = 0.95 GHz	15	25	ı	dB
Output Return Loss 2	RL _{out} 2	P _{in} = 0 dBm, f = 2.15 GHz	10	13	-	dB
POLA Control Threshold Voltage,	V_{th_POLA}	OFF to ON	14	14.75	15.5	V
Channel Selection						
TONE Signal Threshold	V_{th_TONE}	f _{TONE} = 22 kHz, Duty Cycle = 50%,	0.1	0.15	0.35	V_{p-p}
Voltage, Channel Selection		pulse wave, OFF to ON				

Note: Isolation D/U (\underline{D} esire/ \underline{U} n-desire) ratio = |(Signal Leakage (off-state)) - (Insertion loss (on-state))| at Worst mode

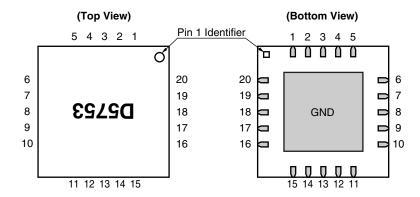
STANDARD CHARACTERISTICS FOR REFERENCE (T_A = +25°C, V_{DD} = +3.3 V, Z_S = Z_L = 50 Ω for each port, Worst mode, unless otherwise specified)

Parameter	Symbol	Test Conditions	Reference Value	Unit
Insertion Loss Flatness	△L _{INS}	L _{INS} 1-L _{INS} 2	1.0	dB
Isolation D/U Ratio 1 Note	ISL _{D/U} 1	P _{in} = 0 dBm, f = 0.95 GHz	40	dB
Input Return Loss 1	RL _{in} 1	P _{in} = 0 dBm, f = 0.95 GHz	20	dB
Input Return Loss 2	RL _{in} 2	P _{in} = 0 dBm, f = 2.15 GHz	14	dB
POLA Control Current	I _{POLA}	V _{POLA} = 21 V	230	μΑ
POLA Switching Time	T _{POLA}	V _{POLA} = 18 V, OFF to ON	0.75	μs
TONE Switching Time	T _{TONE}	f_{TONE} = 22 kHz, Duty Cycle = 50%, pulse wave, V_{TONE} = 600 m V_{p-p} ,	220	μs
		OFF to ON		

Note: Isolation D/U (\underline{D} esire/ \underline{U} n-desire) ratio = |(Signal Leakage (off-state)) - (Insertion loss (on-state))| at Worst mode



PIN CONNECTIONS



Pin No.	Pin Name						
1	TONE1	6	IN-B	11	GND	16	OUT2
2	POLA1	7	GND	12	IN-C	17	M1
3	GND	8	GND	13	GND	18	V_{DD}
4	IN-A	9	GND	14	POLA2	19	MO
5	GND	10	IN-D	15	TONE2	20	OUT1

TRUTH TABLE

SWITCHING CONTROL OF OUT1 SIGNAL PATH

Logic Pattern		CONTRO	OUT1	
Sel	ect	for Ol		
MO	M1	POLA1	TONE1	Output Signal
		No Voltage	22 kHz	None
		No Voltage	0	None
0	0	Low	22 kHz	IN-C
U	U	Low	0	IN-D
		High	0	IN-B
		High	22 kHz	IN-A
		No Voltage	22 kHz	None
		No Voltage	0	None
1	1	Low	22 kHz	IN-A
ı		Low	0	IN-B
		High	0	IN-D
		High	22 kHz	IN-C
		No Voltage	22 kHz	None
		No Voltage	0	None
0		Low	22 kHz	IN-D
U	'	Low	0	IN-C
		High	0	IN-B
		High	22 kHz	IN-A
		No Voltage	22 kHz	None
		No Voltage	0	None
1	0	Low	22 kHz	IN-B
ı	U	Low	0	IN-A
		High	0	IN-D
		High	22 kHz	IN-C

SWITCHING CONTROL OF OUT2 SIGNAL PATH

Logic Pattern		CONTRO	L PINS	OUT2
Sel	ect	for Ol		
MO	M1	POLA2	TONE2	Output Signal
		No Voltage	22 kHz	None
		No Voltage	0	None
0	0	Low	22 kHz	IN-C
	U	Low	0	IN-D
		High	0	IN-B
		High	22 kHz	IN-A
		No Voltage	22 kHz	None
		No Voltage	0	None
1	1 1	Low	22 kHz	IN-A
'		Low	0	IN-B
		High	0	IN-D
		High	22 kHz	IN-C
		No Voltage	22 kHz	None
		No Voltage	0	None
0		Low	22 kHz	IN-D
		Low	0	IN-C
		High	0	IN-B
		High	22 kHz	IN-A
		No Voltage	22 kHz	None
		No Voltage	0	None
	0	Low	22 kHz	IN-B
	0	Low	0	IN-A
		High	0	IN-D
		High	22 kHz	IN-C

Remarks M0, M1: "0": 0 V dc (Connected to GND line)

"1": V_{DD} dc (Connected to V_{DD} line)

 $V_{DD} = + 3.3 \text{ V dc}$

POLA1, 2: "Low" : 9.5 V to 14 V dc

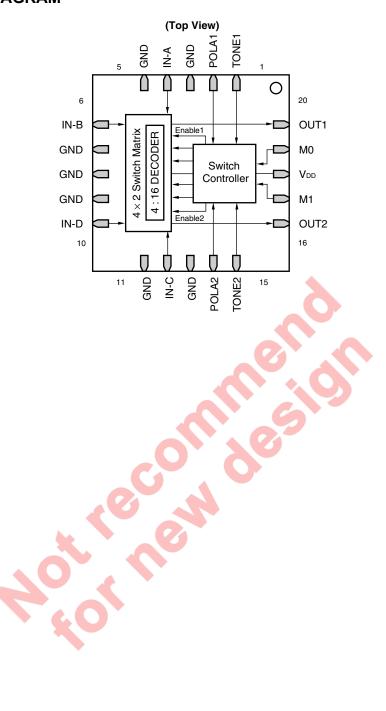
"High" : 15.5 V to 19 V dc

"No Voltage": 0 V dc (< 5 V dc) or Open

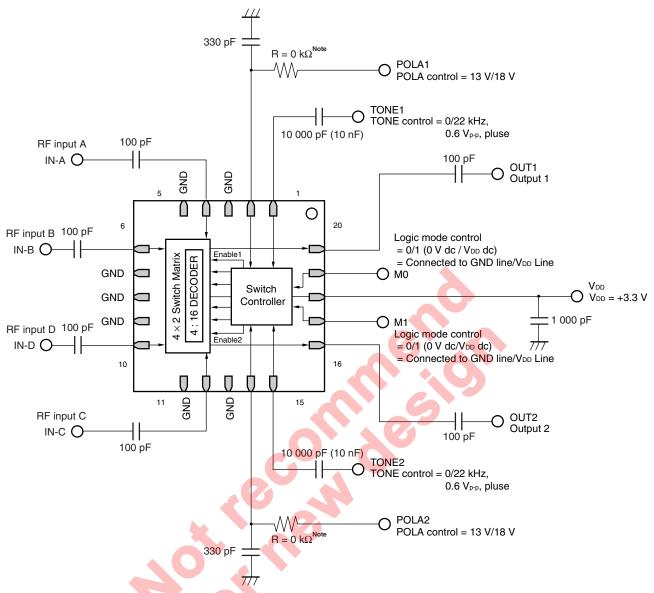
Switch's Enable/Disable function is linked with POLA input voltage level

Switch's Enable condition : $V_{POLA} > 9.5 \text{ V}$

FUNCTIONAL DIAGRAM



EVALUATION CIRCUIT



Note: $R = 0 \text{ k}\Omega \text{ (at POLA control} = 13 \text{ V/18 V})$ = 5.6 k $\Omega \text{ (at POLA control} = 14 \text{ V/18 V})$

Remarks Heat Sink (Bottom Side): GND

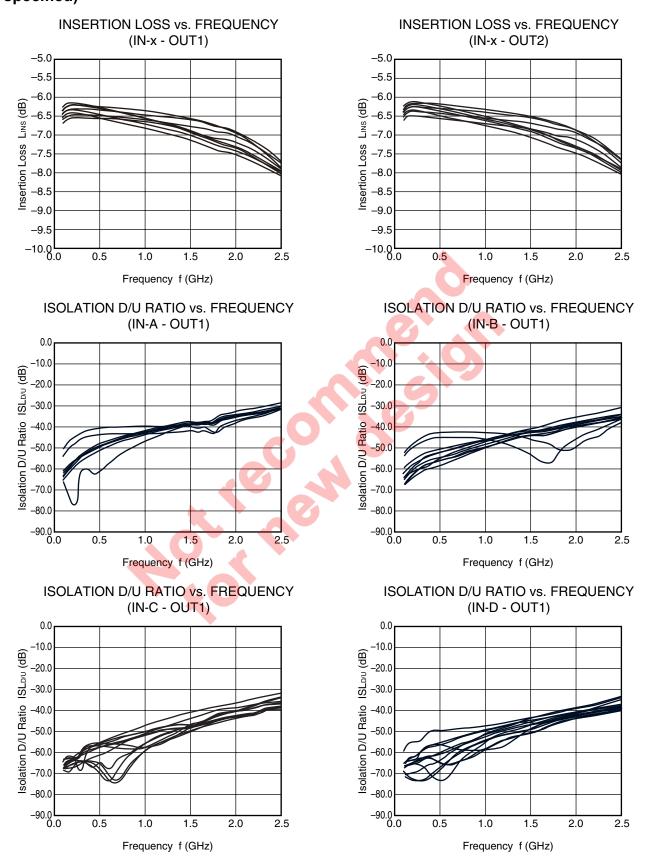
 $Z_S = Z_L = 50 \Omega$

Switch's Enable/Disable function is linked with POLA input voltage level

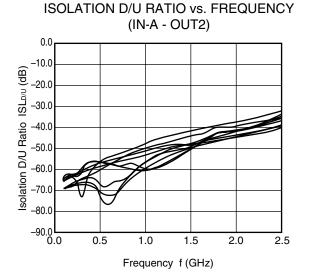
Switch's Enable condition : $V_{POLA} > 9.5 \text{ V}$

The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

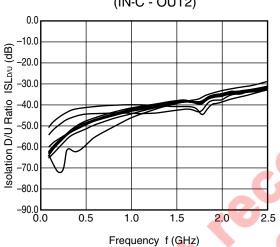
TYPICAL CHARACTERISTICS $(T_A = +25^{\circ}\text{C}, V_{DD} = +3.3 \text{ V}, P_{in} = 0 \text{ dBm}, Z_S = Z_L = 50 \Omega \text{ for each port, unless otherwise specified)}$



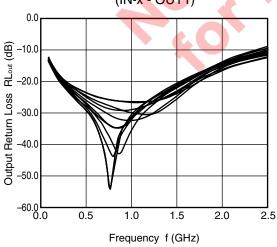
Remark The graphs indicate nominal characteristics.



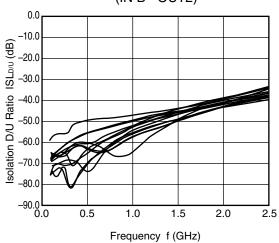




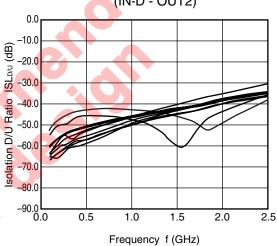
OUTPUT RETURN LOSS vs. FREQUENCY (IN-x - OUT1)



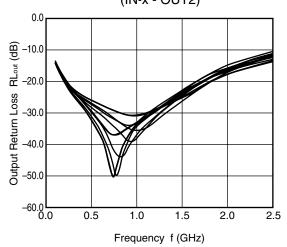
ISOLATION D/U RATIO vs. FREQUENCY (IN-B - OUT2)



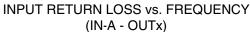
ISOLATION D/U RATIO vs. FREQUENCY (IN-D - OUT2)

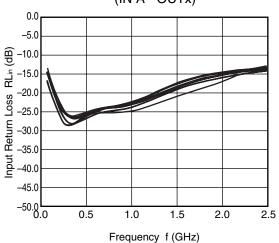


OUTPUT RETURN LOSS vs. FREQUENCY (IN-x - OUT2)

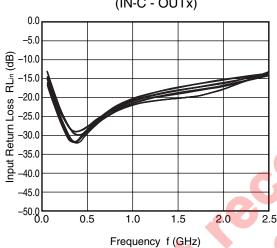


Remark The graphs indicate nominal characteristics.

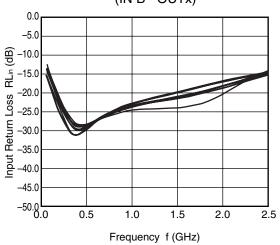




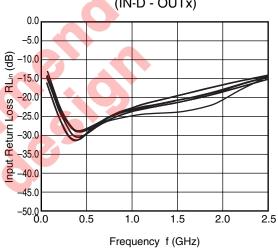
INPUT RETURN LOSS vs. FREQUENCY (IN-C - OUTx)



INPUT RETURN LOSS vs. FREQUENCY (IN-B - OUTx)



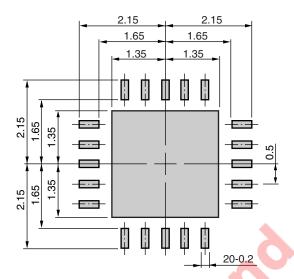
INPUT RETURN LOSS vs. FREQUENCY (IN-D - OUTx)



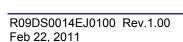
Remark The graphs indicate nominal characteristics.

MOUNTING PAD LAYOUT DIMENSIONS

20-PIN 4×4 mm SQUARE MICRO LEAD PACKAGE (20-PIN PLASTIC QFN (0.5 mm pitch)) (UNIT: mm)



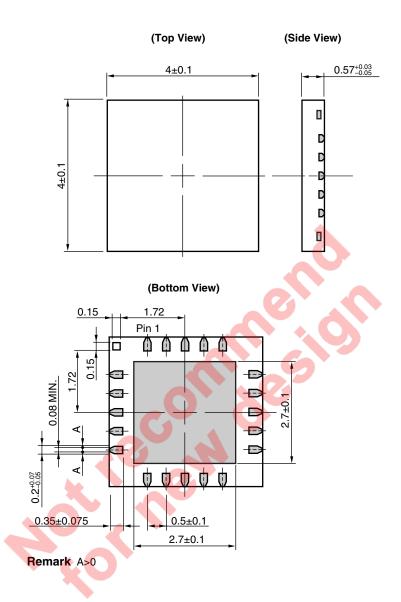
Remark The mounting pad layout in this document is for reference only.





PACKAGE DIMENSIONS

20-PIN 4×4 mm SQUARE MICRO LEAD PACKAGE (20-PIN PLASTIC QFN (0.5 mm pitch)) (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Partial Heating	Peak temperature (package surface temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	

CAUTION

Do not use different soldering methods together (except for partial heating).



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μPD5753T7G Data Sheet

			Description		
Rev.	Date	Page	Summary		
1.00	Feb 22, 2011	-	First edition issued		



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